



QUICKSWITCH® PRODUCTS HIGH-SPEED CMOS 20-BIT LOW RESISTANCE BUS SWITCH

IDTQS32XR384

FEATURES:

- Enhanced N channel FET with no inherent diode to Vcc
- 2.5Ω bidirectional switches connect inputs to outputs
- Zero propagation delay, zero ground bounce
- Undershoot clamp diodes on all switch and control pins
- Two enables control five bits each
- Available in 48-pin QVSOP Package

APPLICATIONS

- Hot-swapping and hot-docking (low resistance for PCI and Compact PCI applications)
- Voltage translation (5V to 3.3V)
- Power conservation
- Capacitance reduction and isolation
- Bus isolation
- Clock gating

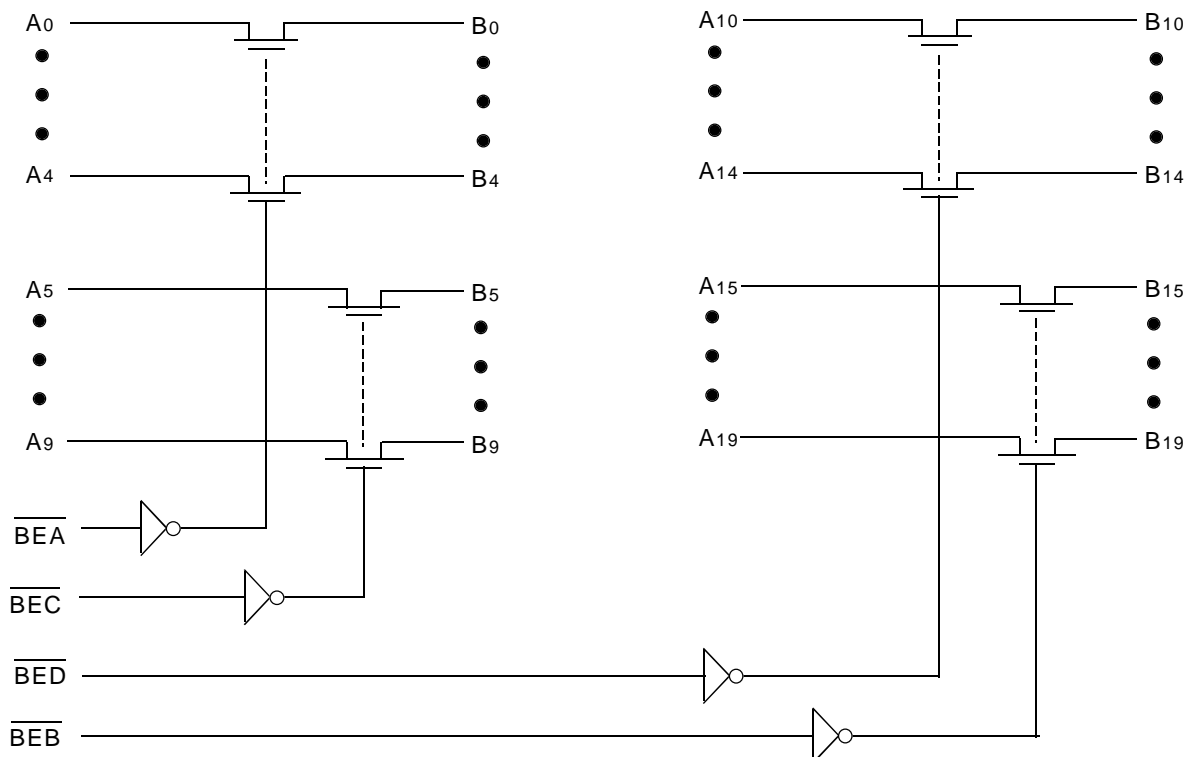
DESCRIPTION:

The QS32XR384 provides two sets of ten high-speed CMOS TTL-compatible bus switches. Four banks of five switches are controlled by independent Bus Enable (\overline{BE}) signals. The very low R_{on} resistance (2.5Ω) of the QS32XR384 allows inputs to be connected without adding propagation delay and without generating additional ground bounce noise.

The QS32XR384 is ideal for switching digital buses, as well as for hot plug buffering and 5V to 3.3V conversion.

The QS32XR384 is characterized for operation at -40°C to $+85^{\circ}\text{C}$.

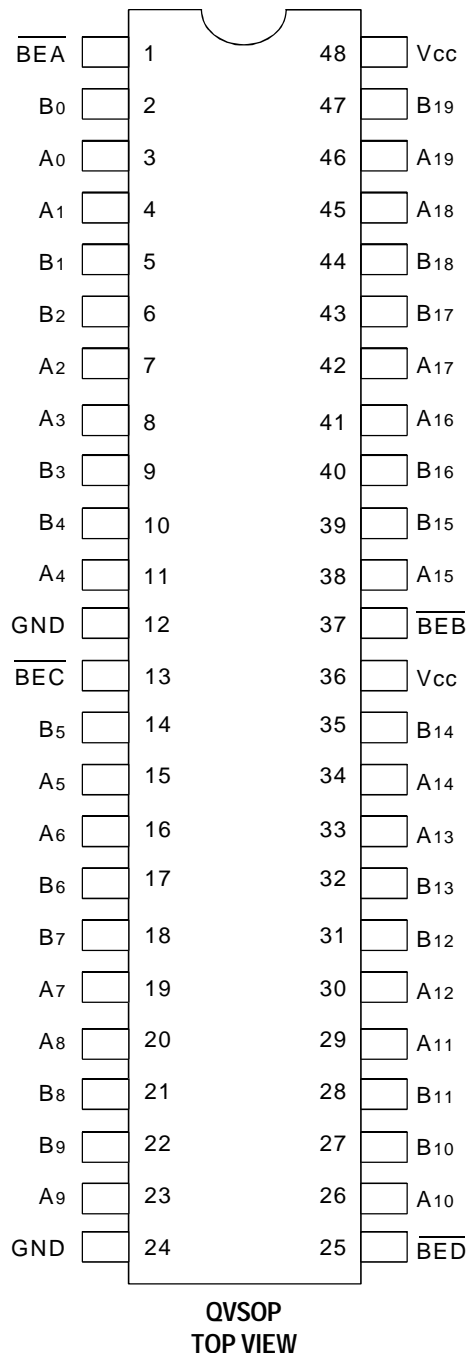
FUNCTIONAL BLOCK DIAGRAM



INDUSTRIAL TEMPERATURE RANGE

NOVEMBER 1999

PIN CONFIGURATION



PIN DESCRIPTION

Pin Names	I/O	Description
A0 - A19	I/O	Bus A
B0 - B19	I/O	Bus B
$\overline{\text{BEA}}$	I	Enable, 0-4
$\overline{\text{BEB}}$	I	Enable, 15-19
$\overline{\text{BEC}}$	I	Enable, 5-9
$\overline{\text{BED}}$	I	Enable, 10-14

ABSOLUTE MAXIMUM RATINGS ⁽¹⁾

Symbol	Description	Max.	Unit
$V_{\text{TERM}}^{(2)}$	Supply Voltage to Ground	- 0.5 to +7	V
$V_{\text{TERM}}^{(3)}$	DC Switch Voltage V_s	- 0.5 to +7	V
$V_{\text{TERM}}^{(3)}$	DC Input Voltage V_{IN}	- 0.5 to +7	V
V_{AC}	AC Input Voltage (pulse width $\leq 20\text{ns}$)	-3	V
I_{OUT}	DC Output Current	120	mA
P_{MAX}	Maximum Power Dissipation	.5	W
T_{STG}	Storage Temperature	- 65 to +150	°C

NOTES:

- Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.
- Vcc Terminals.
- All terminals except Vcc.

CAPACITANCE

($T_A = +25^\circ\text{C}$, $f = 1.0\text{MHz}$, $V_{\text{IN}} = 0\text{V}$, $V_{\text{OUT}} = 0\text{V}$)

Pins	Typ.	Max. ⁽¹⁾	Unit
Control Inputs	3	4	pF
Quickswitch Channels (Switch OFF)	5	6	pF

NOTE:

- This parameter is guaranteed but not production tested.

FUNCTION TABLE ⁽¹⁾

$\overline{\text{BEA}}$	$\overline{\text{BEB}}$	B0 - B4	B15 - B19	Function
H	H	Hi-Z	Hi-Z	Disconnect
L	H	A0 - A4	Hi-Z	Connect
H	L	Hi-Z	A15 - A19	Connect
L	L	A0 - A4	A15 - A19	Connect
$\overline{\text{BEC}}$	$\overline{\text{BED}}$	B5 - B9	B10 - B14	Function
H	H	Hi-Z	Hi-Z	Disconnect
L	H	A5 - A9	Hi-Z	Connect
H	L	Hi-Z	A10 - A14	Connect
L	L	A5 - A9	A10 - A14	Connect

NOTE:

- H = HIGH Voltage Level
L = LOW Voltage Level
Z = High-Impedance

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:

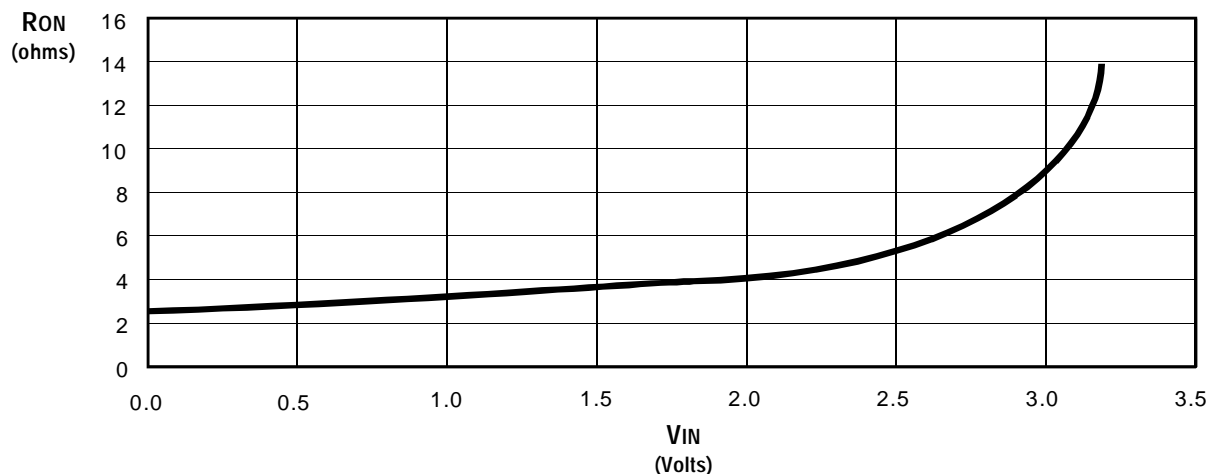
Industrial: $T_A = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$, $V_{CC} = 5.0\text{V} \pm 10\%$

Symbol	Parameter	Test Conditions	Min.	Typ. ⁽¹⁾	Max.	Unit
V_{IH}	Input HIGH Voltage	Guaranteed Logic HIGH for Control Pins	2	—	—	V
V_{IL}	Input LOW Voltage	Guaranteed Logic LOW for Control Pins	—	—	0.8	V
I_{IN}	Input Leakage Current (Control Inputs)	$0\text{V} \leq V_{IN} \leq V_{CC}$	—	± 0.01	± 1	μA
I_{OZ}	Off-State Current (Hi-Z)	$0\text{V} \leq V_{OUT} \leq V_{CC}$, Switches OFF	—	± 0.01	± 1	μA
R_{ON}	Switch ON Resistance	$V_{CC} = \text{Min.}$, $V_{IN} = 0\text{V}$, $I_{ON} = 30\text{mA}$	—	2.5	5	Ω
R_{ON}	Switch ON Resistance	$V_{CC} = \text{Min.}$, $V_{IN} = 2.4\text{V}$, $I_{ON} = 15\text{mA}$	—	4	8.5	Ω
V_P	Pass Voltage ⁽²⁾	$V_{IN} = V_{CC} = 5\text{V}$, $I_{OUT} = -5\mu\text{A}$	3.7	4	4.3	V

NOTES:

1. Typical values are at $V_{CC} = 5.0\text{V}$, $T_A = 25^{\circ}\text{C}$.
2. Pass voltage is guaranteed but not production tested.

TYPICAL ON RESISTANCE vs V_{IN} AT $V_{CC} = 5\text{V}$



POWER SUPPLY CHARACTERISTICS

Symbol	Parameter	Test Conditions ⁽¹⁾	Max.	Unit
I _{CCQ}	Quiescent Power Supply Current	V _{CC} = Max., V _{IN} = GND or V _{CC} , f = 0	3	mA
ΔI _{CC}	Power Supply Current per Control Input HIGH ⁽²⁾	V _{CC} = Max., V _{IN} = 3.4V, f = 0	2.5	mA
I _{CCD}	Dynamic Power Supply Current per MHz ⁽³⁾	V _{CC} = Max., A and B pins open Control Inputs Toggling at 50% Duty Cycle	0.25	mA/MHz

NOTES:

- For conditions shown as Min. or Max., use the appropriate values specified under DC Electrical Characteristics.
- Per TLL driven input (V_{IN} = 3.4V, control inputs only). A and B pins do not contribute to ΔI_{CC}.
- This current applies to the control inputs only and represents the current required to switch internal capacitance at the specified frequency. The A and B inputs generate no significant AC or DC currents as they transition. This parameter is guaranteed but not production tested.

SWITCHING CHARACTERISTICS OVER OPERATING RANGE

T_A = -40°C to +85°C, V_{CC} = 5.0V ± 10%

C_{LOAD} = 50pF, R_{LOAD} = 500Ω unless otherwise noted.

Symbol	Parameter	Min. ⁽¹⁾	Typ.	Max.	Unit
t _{PLH} t _{PHL}	Data Propagation Delay ^(2,4) Ax to Bx, Bx to Ax	—	—	0.12 ⁽³⁾	ns
t _{PZL} t _{PZH}	Switch Turn-on Delay $\overline{\text{BEA}}$, $\overline{\text{BEB}}$ to Ax, Bx	1.5	—	6	ns
t _{PLZ} t _{PHZ}	Switch Turn-off Delay ⁽²⁾ $\overline{\text{BEA}}$, $\overline{\text{BEB}}$ to Ax, Bx	1.5	—	4	ns

NOTES:

- Minimums are guaranteed but not production tested.
- This parameter is guaranteed but not production tested.
- The time constant for the switch alone is of the order of 0.12ns for C_L = 50pF.
- The bus switch contributes no propagation delay other than the RC delay of the ON resistance of the switch and the load capacitance. Since this time constant is much smaller than the rise and fall times of typical driving signals, it adds very little propagation delay to the system. Propagation delay of the bus switch, when used in a system, is determined by the driving circuit on the driving side of the switch and its interaction with the load on the driven side.

ORDERING INFORMATION

IDTQS	XXXXX	XX	X		
Device	Type	Package	Process		
			Blank	Industrial (-40°C to +85°C)	
		Q1		48-pin QVSOP	
			32XR384	High Speed CMOS 20-Bit Low Resistance Bus Switch	



CORPORATE HEADQUARTERS
2975 Stender Way
Santa Clara, CA 95054

for SALES:
800-345-7015 or 408-727-6116
fax: 408-492-8674
www.idt.com*

**To search for sales office near you, please click the sales button found on our home page or dial the 800# above and press 2.
The IDT logo, QuickSwitch, and SynchroSwitch are registered trademarks of Integrated Device Technology, Inc.*